

## AD8661/AD8662/AD8664

### FEATURES

**Low offset voltage:** 100  $\mu\text{V}$  maximum @  $V_S = 5\text{ V}$

**Low input bias current:** 1 pA maximum

**Single-supply operation:** 5 V to 16 V

**Low noise:** 10 nV/ $\sqrt{\text{Hz}}$

**Wide bandwidth:** 4 MHz

**Unity-gain stable**

**Small package options**

3 mm  $\times$  3 mm 8-lead LFCSP

8-lead MSOP and narrow SOIC

14-lead TSSOP and narrow SOIC

### APPLICATIONS

Sensors

Medical equipment

Consumer audio

Photodiode amplification

ADC drivers

### PIN CONFIGURATIONS

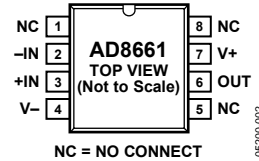


Figure 1. AD8661, 8-Lead SOIC\_N (R-8)

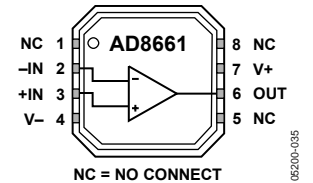


Figure 2. AD8661, 8-Lead LFCSP\_VD (CP-8-2)

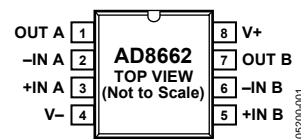


Figure 3. AD8662, 8-Lead SOIC\_N (R-8)



Figure 4. AD8662, 8-Lead MSOP (RM-8)

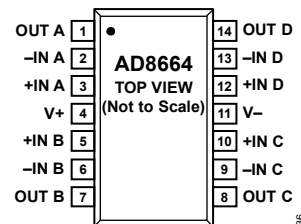


Figure 5. AD8664, 14-Lead SOIC\_N (R-14)

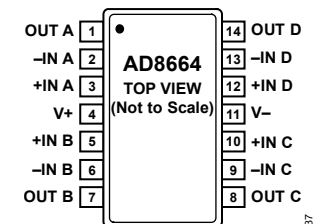


Figure 6. AD8664, 14-Lead TSSOP (RU-14)

### GENERAL DESCRIPTION

The AD8661/AD8662/AD8664 are rail-to-rail output, single-supply amplifiers that use the Analog Devices, Inc., patented DigiTrim<sup>®</sup> trimming technique to achieve low offset voltage. The AD866x series features extended operating ranges, with supply voltages up to 16 V. It also features low input bias current, wide signal bandwidth, and low input voltage and current noise.

The combination of low offset, very low input bias current, and a wide supply range makes these amplifiers useful in a wide variety of applications usually associated with higher priced JFET amplifiers. Systems using high impedance sensors, such as photodiodes, benefit from the combination of low input bias current, low noise, low offset, and wide bandwidth. The wide operating voltage range meets the demands of high performance ADCs and DACs. Audio applications and medical

monitoring equipment can take advantage of the high input impedance, low voltage and current noise, and wide bandwidth.

The single AD8661 is available in a narrow 8-lead SOIC package and a very thin, dual lead, 8-lead LFCSP. The AD8661 SOIC\_N package is specified over the extended industrial temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ . The AD8661 LFCSP\_VD is specified over the industrial temperature range of  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ . The AD8662 is available in a narrow 8-lead SOIC package and an 8-lead MSOP, both specified over the extended industrial temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ . The AD8664 is available in a narrow 14-lead SOIC package and a 14-lead TSSOP, both with an extended industrial temperature range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .

#### Rev. D

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## REVISION HISTORY

### 7/06—Rev. C to Rev. D

Added AD8664 .....	Universal
Added 14-Lead SOIC_N and 14-Lead TSSOP .....	Universal
Changes to Features.....	1
Changes to Table 1 .....	3
Changes to Table 2.....	4
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Changes to Figure 29.....	11
Updated Outline Dimensions .....	13
Changes to Ordering Guide .....	15

### 5/06—Rev. B to Rev. C

Changes to Ordering Guide .....	13
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### 3/06—Rev. A to Rev. B

Added AD8662 .....	Universal
Added MSOP .....	Universal

Changes to Table 1 .....	3
Changes to Table 2.....	4
Changes to Table 3.....	5
Changes to Table 4.....	6
Changes to Table 5.....	7
Updated Outline Dimensions .....	13
Changes to Ordering Guide .....	13

### 1/06—Rev. 0 to Rev. A

Added LFCSP_VD .....	Universal
Changes to Table 1.....	3
Changes to Table 2.....	4
Changes to Ordering Guide .....	13

### 9/05—Revision 0: Initial Version

## SPECIFICATIONS

### AD8661/AD8662/AD8664 ELECTRICAL CHARACTERISTICS—SOIC\_N, MSOP, AND TSSOP

$V_S = 5.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 1.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$V_{CM} = V_S/2$		30	100	$\mu\text{V}$
AD8661		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			1000	$\mu\text{V}$
AD8661		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			1400	$\mu\text{V}$
AD8662		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			1000	$\mu\text{V}$
AD8664		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			1200	$\mu\text{V}$
Input Bias Current	$I_B$			0.3	1	$\text{pA}$
		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			50	$\text{pA}$
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			300	$\text{pA}$
Input Offset Current	$I_{OS}$			0.2	0.5	$\text{pA}$
		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			20	$\text{pA}$
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			75	$\text{pA}$
Input Voltage Range			-0.1		+3.0	$\text{V}$
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.1\text{ V to }+3.0\text{ V}$	85	100		$\text{dB}$
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	80	100		$\text{dB}$
Large Signal Voltage Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }4.5\text{ V}$	100	220		$\text{V/mV}$
Offset Voltage Drift	$TCV_{OS}$					$\mu\text{V}/^\circ\text{C}$
AD8661		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		3	10	$\mu\text{V}/^\circ\text{C}$
AD8662, AD8664		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		2	9	$\mu\text{V}/^\circ\text{C}$
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$I_L = 1\text{ mA}$	4.85	4.93		$\text{V}$
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	4.80			$\text{V}$
Output Voltage Low	$V_{OL}$	$I_L = 1\text{ mA}$		50	100	$\text{mV}$
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			110	$\text{mV}$
Short-Circuit Current	$I_{SC}$			$\pm 19$		$\text{mA}$
Closed-Loop Output Impedance	$Z_{OUT}$	$f = 1\text{ MHz}$ , $A_V = 1$		50		$\Omega$
<b>POWER SUPPLY</b>						
Supply Current per Amplifier	$I_{SY}$	$V_O = V_S/2$		1.15	1.40	$\text{mA}$
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			2.0	$\text{mA}$
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		3.5		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			4		$\text{MHz}$
Phase Margin	$\Phi_O$			65		Degrees
<b>NOISE PERFORMANCE</b>						
Peak-to-Peak Noise	$e_n\text{ p-p}$	$f = 0.1\text{ Hz to }10\text{ Hz}$		2.5		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		12		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		10		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 1\text{ kHz}$		0.1		$\text{pA}/\sqrt{\text{Hz}}$

# AD8661/AD8662/AD8664

## AD8661/AD8662/AD8664 ELECTRICAL CHARACTERISTICS—SOIC\_N, MSOP, AND TSSOP

$V_S = 16.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 2.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$V_{CM} = V_S/2$		50	160	$\mu\text{V}$
AD8661		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			1000	$\mu\text{V}$
AD8661		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			1400	$\mu\text{V}$
AD8662		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			1000	$\mu\text{V}$
AD8664		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			1200	$\mu\text{V}$
Input Bias Current	$I_B$			0.3	1	$\text{pA}$
		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			50	$\text{pA}$
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			300	$\text{pA}$
Input Offset Current	$I_{OS}$			0.2	0.5	$\text{pA}$
		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			20	$\text{pA}$
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			75	$\text{pA}$
Input Voltage Range			-0.1		+14.0	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.1\text{ V to }+14.0\text{ V}$	90	110		dB
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	90	110		dB
Large Signal Voltage Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }15.5\text{ V}$	200	360		V/mV
Offset Voltage Drift	$TCV_{OS}$					$\mu\text{V}/^\circ\text{C}$
AD8661		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		3	10	$\mu\text{V}/^\circ\text{C}$
AD8662, AD8664		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$		2	9	$\mu\text{V}/^\circ\text{C}$
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$I_L = 1\text{ mA}$	15.93	15.97		V
		$I_L = 10\text{ mA}$	15.60	15.70		V
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	15.50			V
Output Voltage Low	$V_{OL}$	$I_L = 1\text{ mA}$		24	50	mV
		$I_L = 10\text{ mA}$		190	300	mV
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			350	mV
Short-Circuit Current	$I_{SC}$			$\pm 140$		mA
Closed-Loop Output Impedance	$Z_{OUT}$	$f = 1\text{ MHz}$ , $A_V = 1$		45		$\Omega$
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = 5\text{ V to }16\text{ V}$	95	110		dB
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$	95	115		dB
Supply Current per Amplifier	$I_{SY}$	$V_O = V_S/2$		1.25	1.55	mA
		$-40^\circ\text{C} < T_A < +125^\circ\text{C}$			2.1	mA
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		3.5		V/ $\mu\text{s}$
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	$\Phi_O$			65		Degrees
<b>NOISE PERFORMANCE</b>						
Peak-to-Peak Noise	$e_n\text{ p-p}$	$f = 0.1\text{ Hz to }10\text{ Hz}$		2.5		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		12		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		10		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 1\text{ kHz}$		0.1		$\text{pA}/\sqrt{\text{Hz}}$

**AD8661 ELECTRICAL CHARACTERISTICS—LFCSP\_VD ONLY**

$V_S = 5.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

**Table 3.**

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$V_{CM} = V_S/2$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$		50	300	$\mu\text{V}$
Input Bias Current	$I_B$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$		0.3	1	$\mu\text{V}$
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$			50	$\mu\text{V}$
Input Voltage Range		$-40^\circ\text{C} < T_A < +85^\circ\text{C}$		0.2	0.5	$\mu\text{V}$
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.1\text{ V to }+3.0\text{ V}$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$	-0.1	85	100	$\mu\text{V}$
Large Signal Voltage Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }4.5\text{ V}$	80	100		dB
Offset Voltage Drift	$TCV_{OS}$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$	100	240		dB
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$I_L = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$	4.85	4.93		V
Output Voltage Low	$V_{OL}$	$I_L = 1\text{ mA}$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$	4.80	50	100	V
Short-Circuit Current	$I_{SC}$			$\pm 19$	120	mV
Closed-Loop Output Impedance	$Z_{OUT}$	$f = 1\text{ MHz}$ , $A_V = 1$		65		mV
<b>POWER SUPPLY</b>						
Supply Current per Amplifier	$I_{SY}$	$V_O = V_S/2$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$		1.15	1.40	mA
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		3.5		$\mu\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	$\Phi_O$			65		Degrees
<b>NOISE PERFORMANCE</b>						
Peak-to-Peak Noise	$e_n$ p-p	$f = 0.1\text{ Hz to }10\text{ Hz}$		2.5		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$		12		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 10\text{ kHz}$		10		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 1\text{ kHz}$		0.1		$\text{pA}/\sqrt{\text{Hz}}$

# AD8661/AD8662/AD8664

## AD8661 ELECTRICAL CHARACTERISTICS—LFCSP\_VD ONLY

$V_S = 16.0\text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

Table 4.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
<b>INPUT CHARACTERISTICS</b>						
Offset Voltage	$V_{OS}$	$V_{CM} = V_S/2$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$		50	300	$\mu\text{V}$
Input Bias Current	$I_B$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$		0.3	1	$\mu\text{A}$
Input Offset Current	$I_{OS}$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$		0.2	0.5	$\mu\text{A}$
Input Voltage Range			-0.1		+14.0	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -0.1\text{ V to }+14.0\text{ V}$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$	90	110		dB
Large Signal Voltage Gain	$A_{VO}$	$R_L = 2\text{ k}\Omega$ , $V_O = 0.5\text{ V to }15.5\text{ V}$	200	420		V/mV
Offset Voltage Drift	$TCV_{OS}$	$-40^\circ\text{C} < T_A < +85^\circ\text{C}$		4	17	$\mu\text{V}/^\circ\text{C}$
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage High	$V_{OH}$	$I_L = 1\text{ mA}$ $I_L = 10\text{ mA}$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$	15.95 15.60 15.50	15.97 15.70		V V V
Output Voltage Low	$V_{OL}$	$I_L = 1\text{ mA}$ $I_L = 10\text{ mA}$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$		24 210	50 350	mV mV mV
Short-Circuit Current	$I_{SC}$			$\pm 140$		mA
Closed-Loop Output Impedance	$Z_{OUT}$	$f = 1\text{ MHz}$ , $A_V = 1$		45		$\Omega$
<b>POWER SUPPLY</b>						
Power Supply Rejection Ratio	PSRR	$V_S = 5\text{ V to }16\text{ V}$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$	95 95	110 115		dB dB
Supply Current per Amplifier	$I_{SY}$	$V_O = V_S/2$ $-40^\circ\text{C} < T_A < +85^\circ\text{C}$		1.25	1.55 1.9	mA mA
<b>DYNAMIC PERFORMANCE</b>						
Slew Rate	SR	$R_L = 2\text{ k}\Omega$		3.5		V/ $\mu\text{s}$
Gain Bandwidth Product	GBP			4		MHz
Phase Margin	$\Phi_O$			65		Degrees
<b>NOISE PERFORMANCE</b>						
Peak-to-Peak Noise	$e_n\text{ p-p}$	$f = 0.1\text{ Hz to }10\text{ Hz}$		2.5		$\mu\text{V p-p}$
Voltage Noise Density	$e_n$	$f = 1\text{ kHz}$ $f = 10\text{ kHz}$		12 10		$\text{nV}/\sqrt{\text{Hz}}$ $\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	$i_n$	$f = 1\text{ kHz}$		0.1		$\text{pA}/\sqrt{\text{Hz}}$

## ABSOLUTE MAXIMUM RATINGS

Table 5.

Parameter	Rating
Supply Voltage	18 V
Input Voltage	-0.1 V to $V_S$
Differential Input Voltage	18 V
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range	-60°C to +150°C
Operating Temperature Range	
R-8, RM-8, R-14, and RU-14	-40°C to +125°C
CP-8-2	-40°C to +85°C
Junction Temperature Range	-65°C to +150°C
Lead Temperature, Soldering (60 sec)	300°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



### THERMAL RESISTANCE

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 6. Thermal Resistance

Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
8-Lead SOIC_N	121	43	°C/W
8-Lead LFCSP_VD	75 <sup>1</sup>	18 <sup>1</sup>	°C/W
8-Lead MSOP	142	44	°C/W
14-Lead SOIC_N	88.2	56.3	°C/W
14-Lead TSSOP	114	23.3	°C/W

<sup>1</sup> Exposed pad soldered to application board.

## TYPICAL PERFORMANCE CHARACTERISTICS

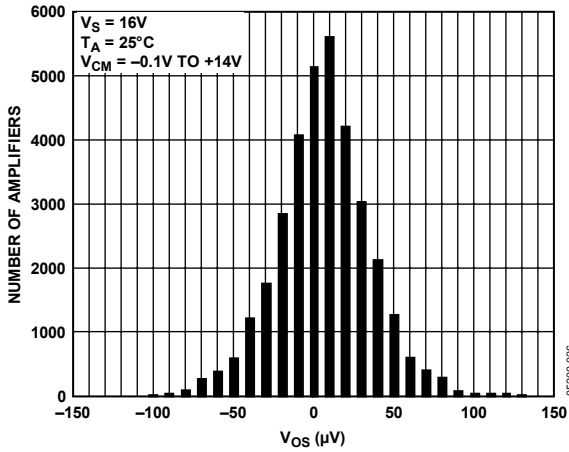


Figure 7. Input Offset Voltage Distribution

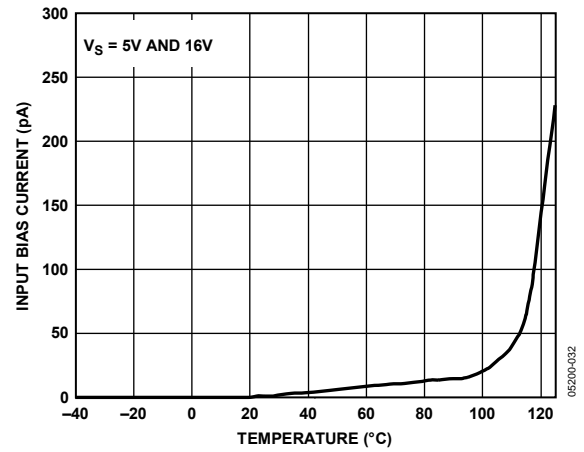


Figure 10. Input Bias Current vs. Temperature

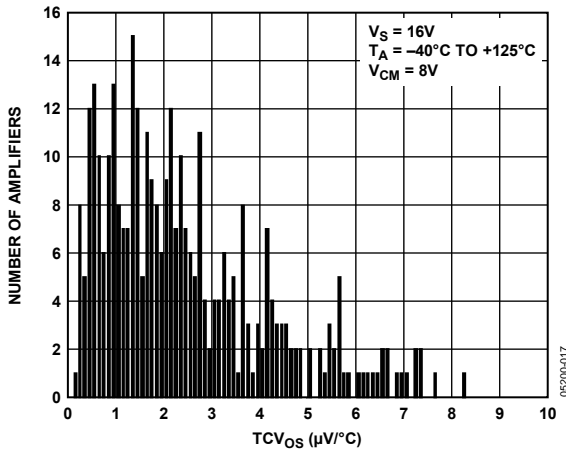


Figure 8. Offset Voltage Drift Distribution

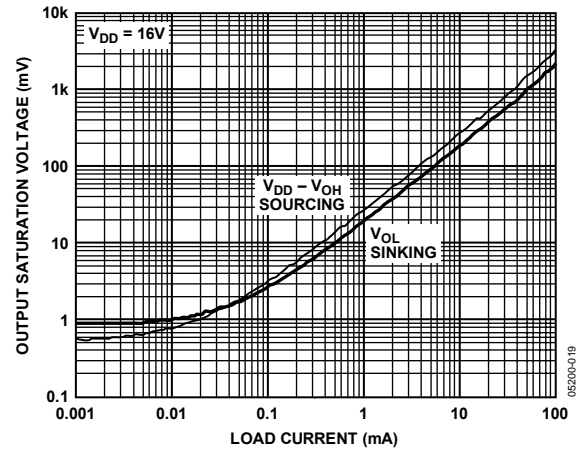


Figure 11. Output Swing Saturation Voltage vs. Load Current

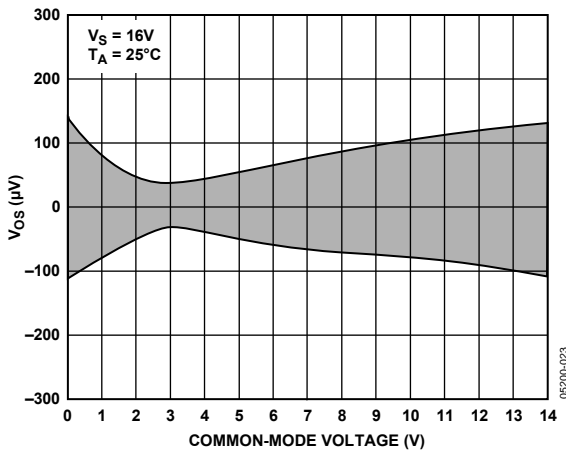


Figure 9. Input Offset Voltage vs. Common-Mode Voltage

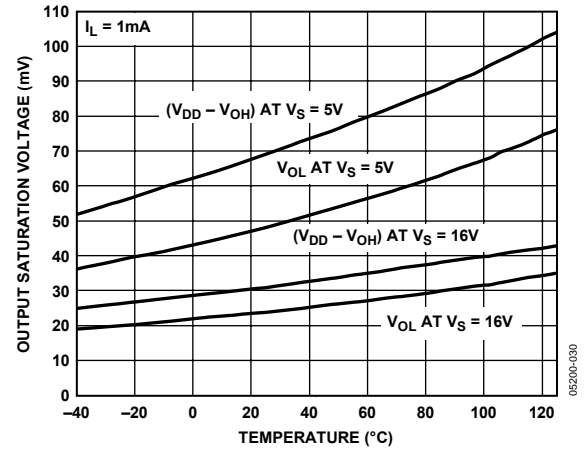


Figure 12. Output Swing Saturation Voltage vs. Temperature,  $I_L = 1\text{ mA}$



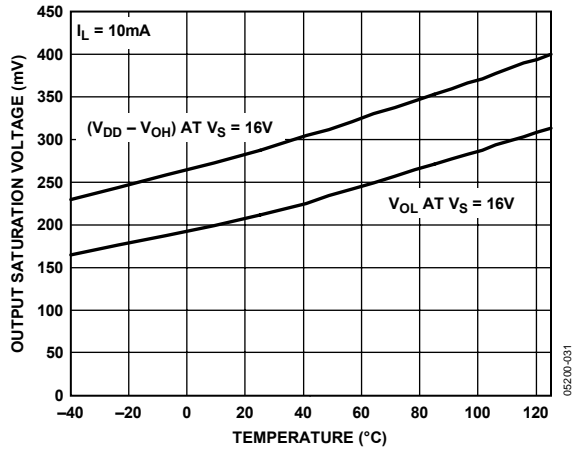


Figure 13. Output Swing Saturation Voltage vs. Temperature,  $I_L = 10\text{ mA}$

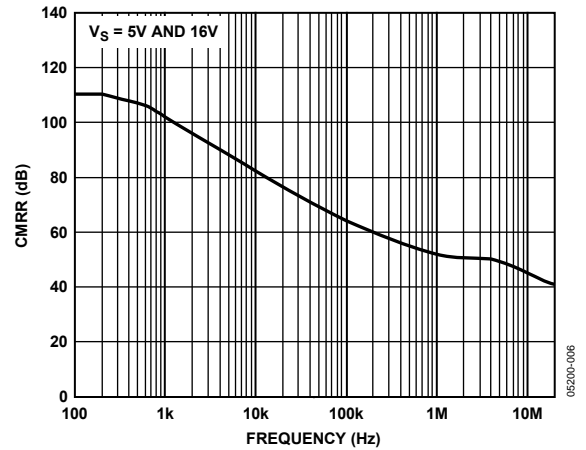


Figure 16. CMRR vs. Frequency

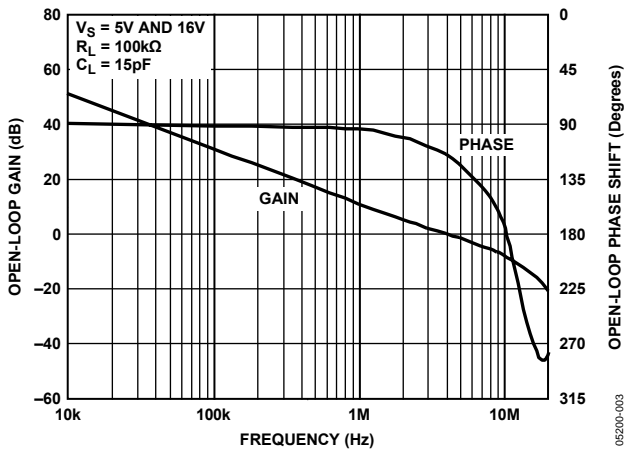


Figure 14. Open-Loop Gain and Phase Shift vs. Frequency

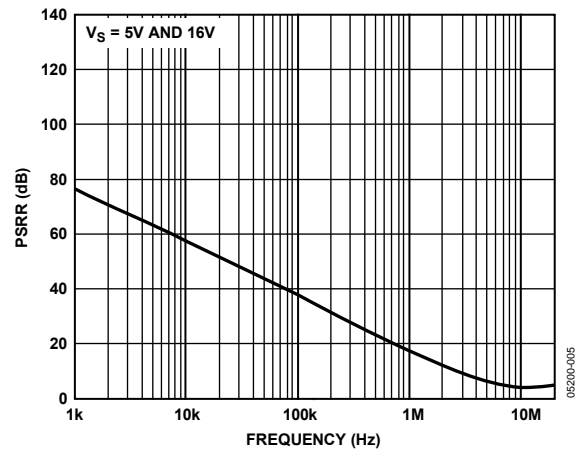


Figure 17. PSRR vs. Frequency

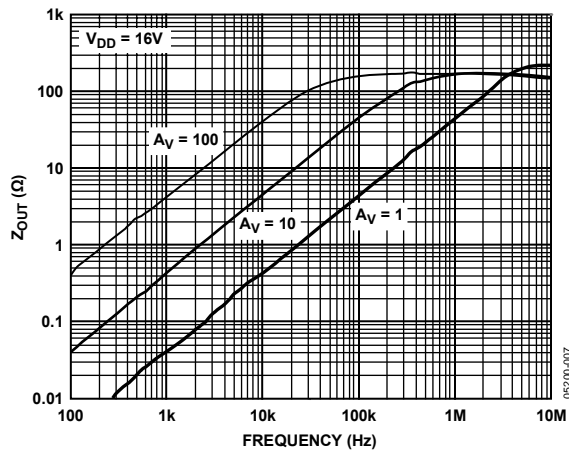


Figure 15. Closed-Loop Output Impedance vs. Frequency

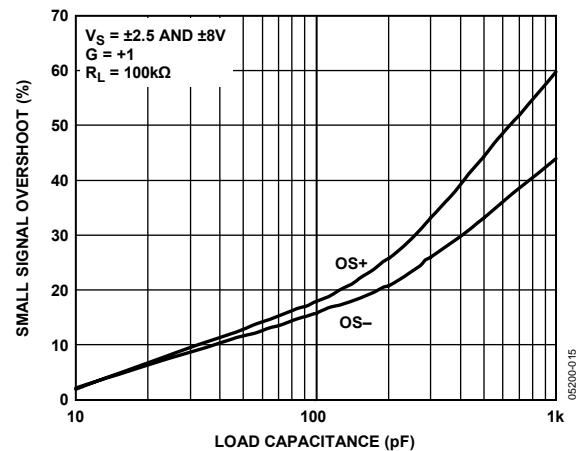


Figure 18. Small Signal Overshoot vs. Load Capacitance

# AD8661/AD8662/AD8664

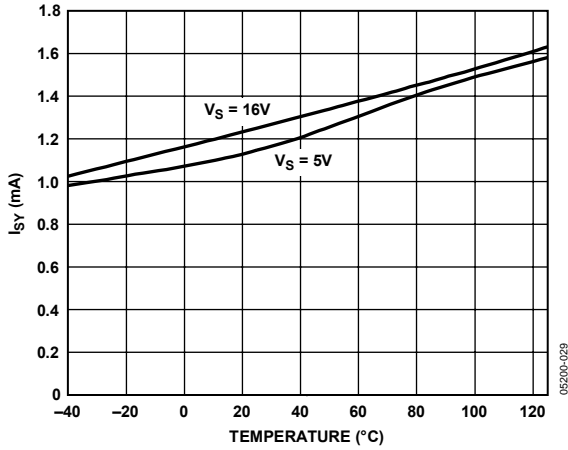


Figure 19. Supply Current vs. Temperature

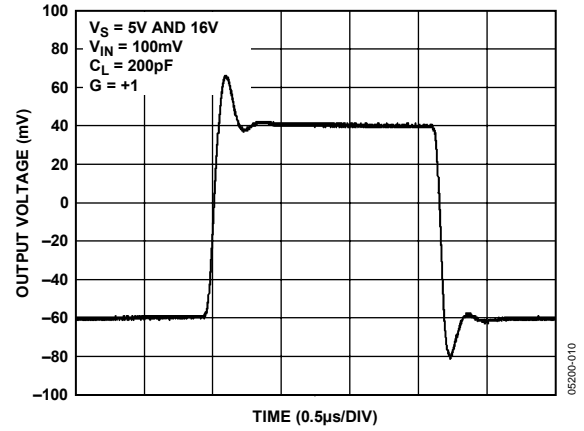


Figure 22. Small Signal Transient Response

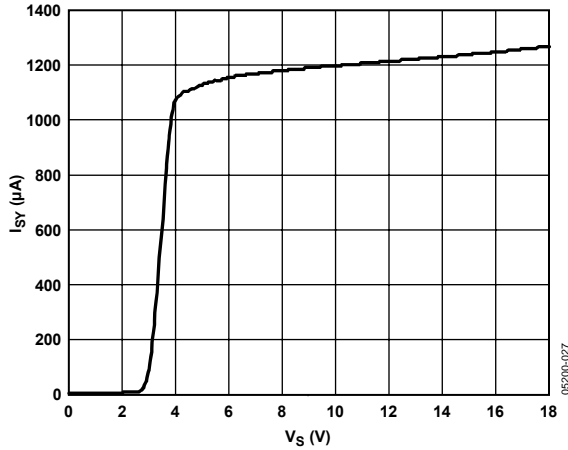


Figure 20. Supply Current vs. Supply Voltage (Dual-Supply Configuration),  $T_A = 25^\circ\text{C}$

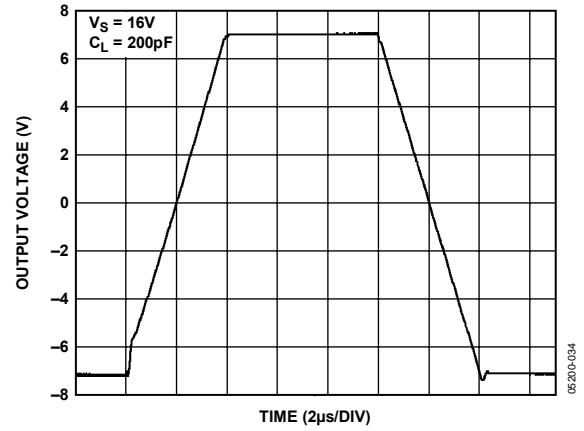


Figure 23. Large Signal Transient Response

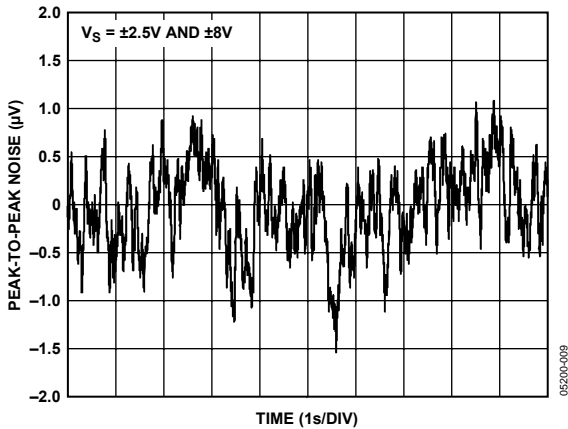


Figure 21. 0.1 Hz to 10 Hz Input Voltage Noise

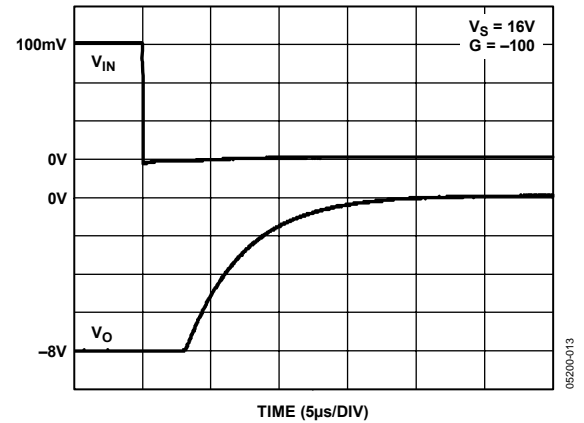


Figure 24. Positive Overload Recovery

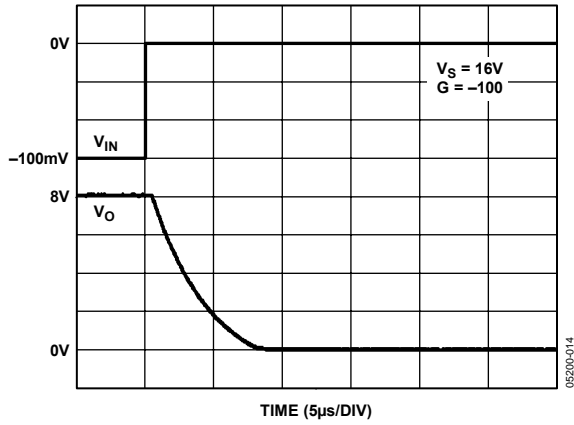


Figure 25. Negative Overload Recovery

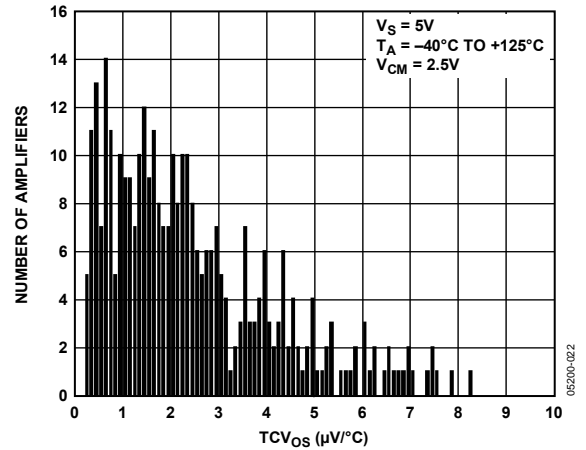


Figure 28. Offset Voltage Drift Distribution

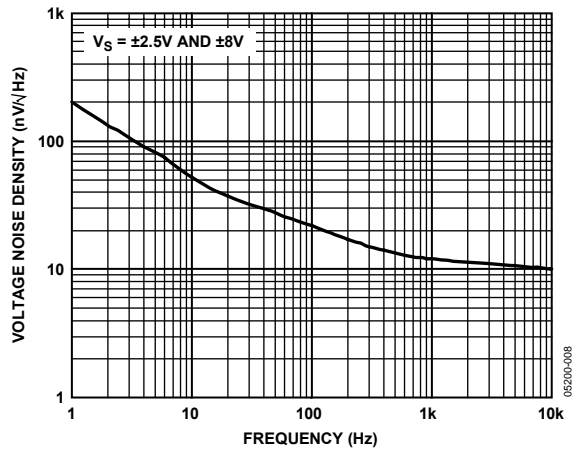


Figure 26. Voltage Noise Density vs. Frequency

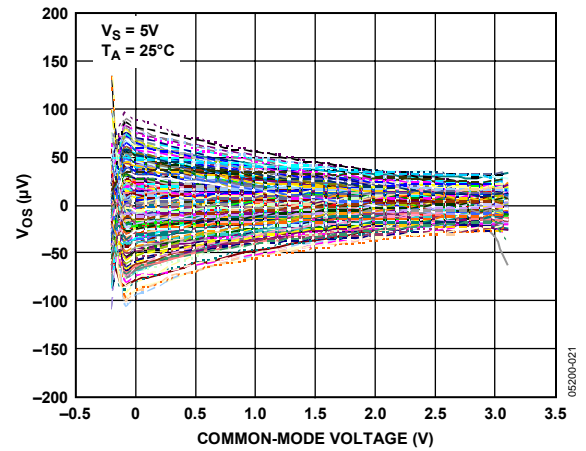


Figure 29. Input Offset Voltage vs. Common-Mode Voltage

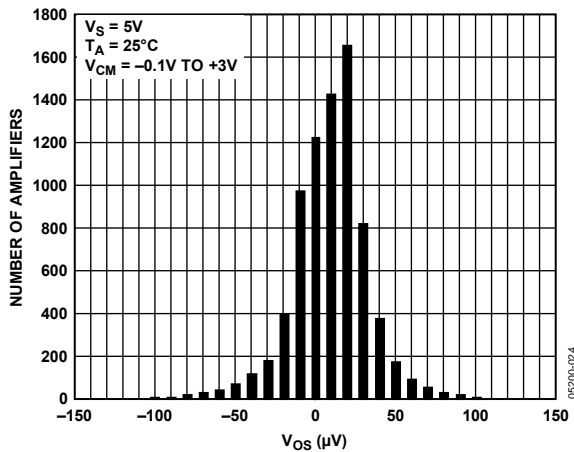


Figure 27. Input Offset Voltage Distribution

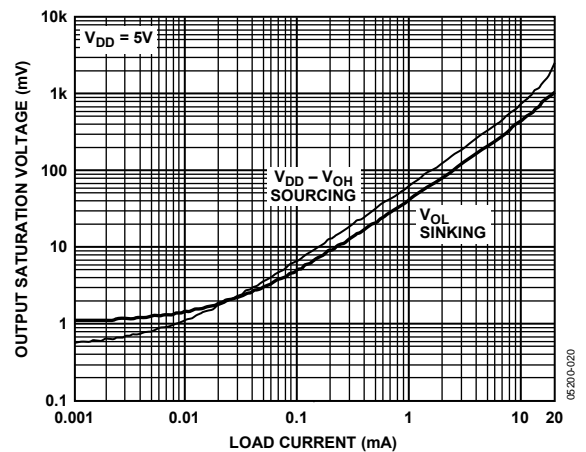


Figure 30. Output Swing Saturation Voltage vs. Load Current

# AD8661/AD8662/AD8664

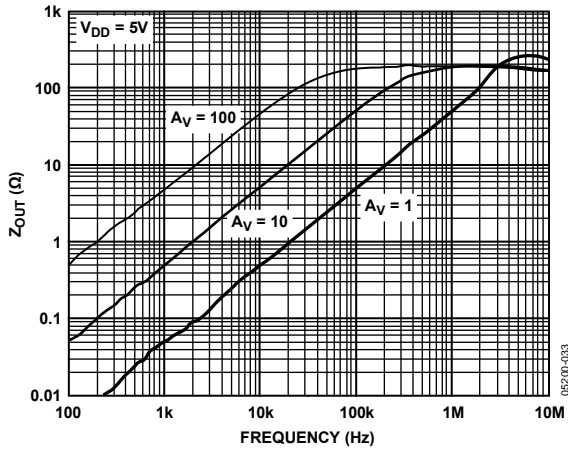


Figure 31. Closed-Loop Output Impedance vs. Frequency

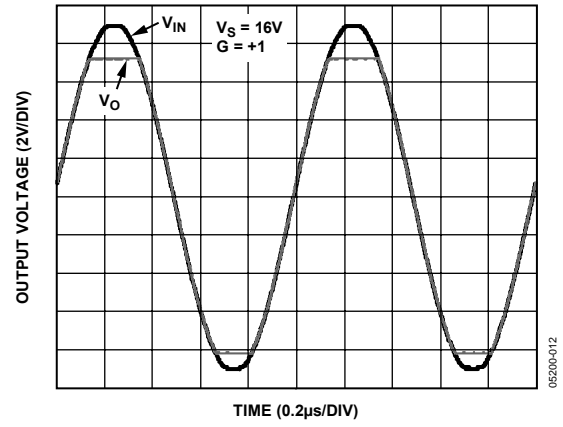


Figure 33. No Phase Reversal

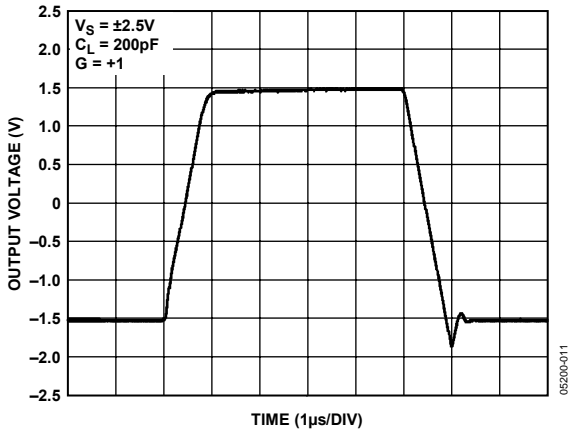
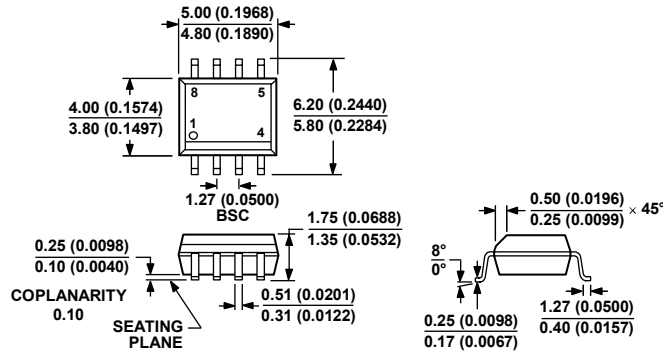


Figure 32. Large Signal Transient Response

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MS-012-AA  
 CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
 (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
 REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

066906-A

Figure 34. 8-Lead Small Outline Package [SOIC\_N]  
 Narrow Body  
 (R-8)

Dimensions shown in millimeters and (inches)

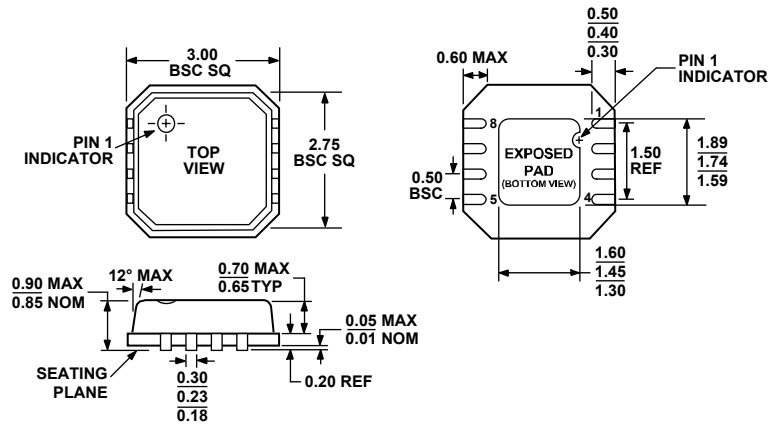
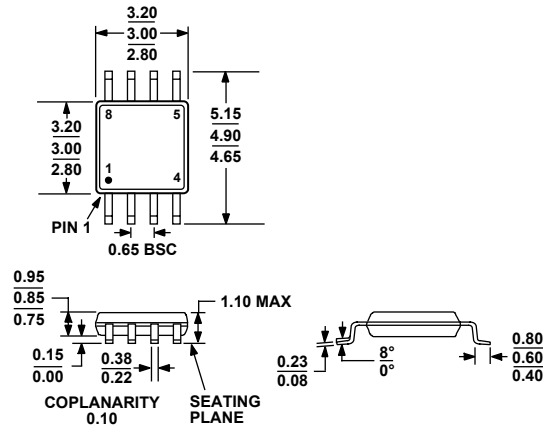


Figure 35. 8-Lead Lead Frame Chip Scale Package [LFCSP\_VD]  
 3 mm x 3 mm Body, Very Thin, Dual Lead  
 (CP-8-2)

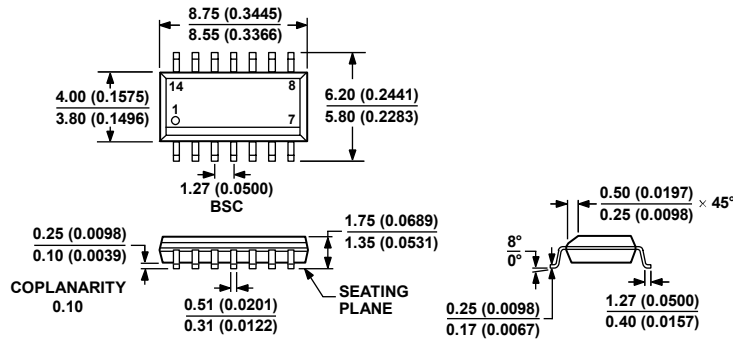
Dimensions shown in millimeters

# AD8661/AD8662/AD8664



COMPLIANT TO JEDEC STANDARDS MO-187-AA

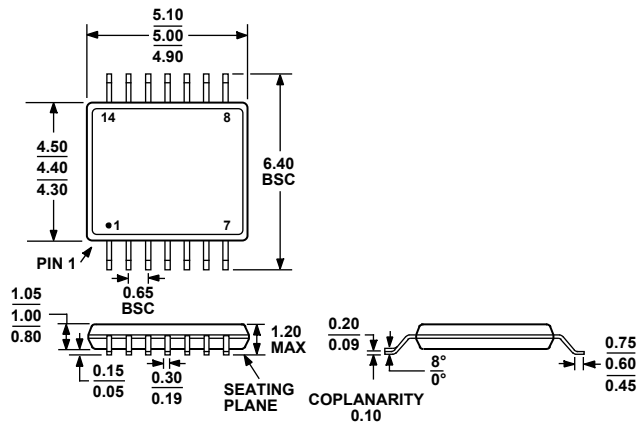
Figure 36. 8-Lead Mini Small Outline Package [MSOP]  
(RM-8)  
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MS-012-AB  
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS  
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR  
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 37. 14-Lead Standard Small Outline Package [SOIC\_N]  
Narrow Body  
(R-14)  
Dimensions shown in millimeters and (inches)

060606-A



COMPLIANT TO JEDEC STANDARDS MO-153-AB-1

Figure 38. 14-Lead Thin Shrink Small Outline Package [TSSOP]  
(RU-14)  
Dimensions shown in millimeters

**ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option	Branding
AD8661ARZ <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8661ARZ-REEL <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8661ARZ-REEL7 <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8661ACPZ-R2 <sup>1</sup>	-40°C to +85°C	8-Lead LFCSP_VD	CP-8-2	A0M
AD8661ACPZ-REEL <sup>1</sup>	-40°C to +85°C	8-Lead LFCSP_VD	CP-8-2	A0M
AD8661ACPZ-REEL7 <sup>1</sup>	-40°C to +85°C	8-Lead LFCSP_VD	CP-8-2	A0M
AD8662ARZ <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8662ARZ-REEL <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8662ARZ-REEL7 <sup>1</sup>	-40°C to +125°C	8-Lead SOIC_N	R-8	
AD8662ARMZ-R2 <sup>1</sup>	-40°C to +125°C	8-Lead MSOP	RM-8	A10
AD8662ARMZ-REEL <sup>1</sup>	-40°C to +125°C	8-Lead MSOP	RM-8	A10
AD8664ARZ <sup>1</sup>	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8664ARZ-REEL <sup>1</sup>	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8664ARZ-REEL7 <sup>1</sup>	-40°C to +125°C	14-Lead SOIC_N	R-14	
AD8664ARUZ <sup>1</sup>	-40°C to +125°C	14-Lead TSSOP	RU-14	
AD8664ARUZ-REEL <sup>1</sup>	-40°C to +125°C	14-Lead TSSOP	RU-14	

<sup>1</sup> Z = Pb-free part.

**AD8661/AD8662/AD8664**

## **NOTES**